



PJS6830

20V Dual N-Channel Enhancement Mode MOSFET – ESD Protected

Voltage

20 V

Current

2 A

Features

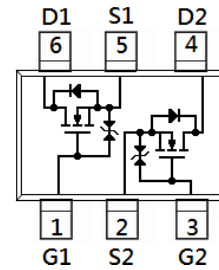
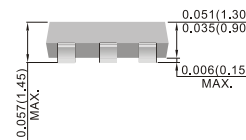
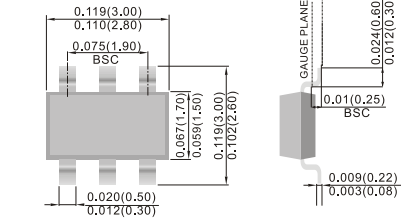
- RDS(ON) , VGS@4.5V, ID@2.0A<150mΩ
- RDS(ON) , VGS@2.5V, ID@1.5A<215mΩ
- RDS(ON) , VGS@1.8V, ID@0.5A<400mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS2.0 (2011/65/EU & 2015/865/EU directive)
- Green molding compound as per IEC61249 Std.. (Halogen Free)

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams

SOT-23 6L

Unit: inch(mm)



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	20	V
Gate-Source Voltage		V _{GS}	±8	V
Continuous Drain Current		I _D	2	A
Pulsed Drain Current (Note 4)		I _{DM}	8	A
Power Dissipation	T _a =25°C	P _D	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance		R _{θJA}	100	°C/W
- Junction to Ambient (Note 3)				



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.8	1.0	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=2.0A$	-	105	150	mΩ
		$V_{GS}=2.5V, I_D=1.5A$	-	150	215	
		$V_{GS}=1.8V, I_D=0.5A$	-	250	400	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=20V, V_{GS}=0V$	-	0.01	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	-	±2	±10	μA
Dynamic (Note 5)						
Total Gate Charge	Q_g	$V_{DS}=10V, I_D=2A,$ $V_{GS}=4.5V$ (Note 1,2)	-	1.8	-	nC
Gate-Source Charge	Q_{gs}		-	0.4	-	
Gate-Drain Charge	Q_{gd}		-	0.45	-	
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V,$ $f=1.0MHz$	-	92	-	pF
Output Capacitance	C_{oss}		-	25	-	
Reverse Transfer Capacitance	C_{rss}		-	9.1	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=10V, I_D=2A,$ $V_{GS}=4.5V,$ $R_G=6\Omega$ (Note 1,2)	-	6.5	-	ns
Turn-On Rise Time	t_r		-	26.5	-	
Turn-Off Delay Time	$t_{d(off)}$		-	43	-	
Turn-Off Fall Time	t_f		-	34	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	1.6	A
Diode Forward Voltage	V_{SD}	$I_S=1.6A, V_{GS}=0V$	-	0.9	1.2	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

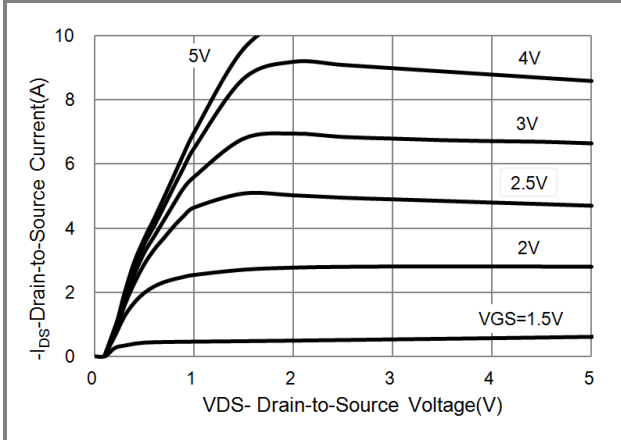


Fig.1 On-Region Characteristics

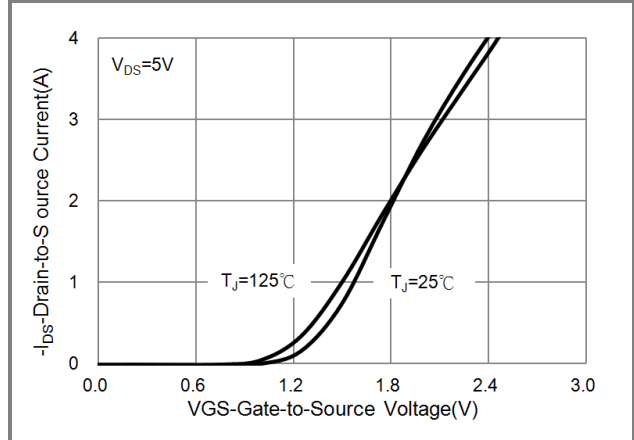


Fig.2 Transfer Characteristics

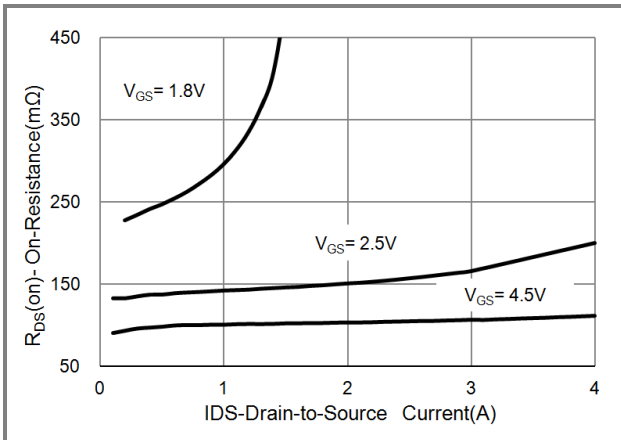


Fig.3 On-Resistance vs. Drain Current

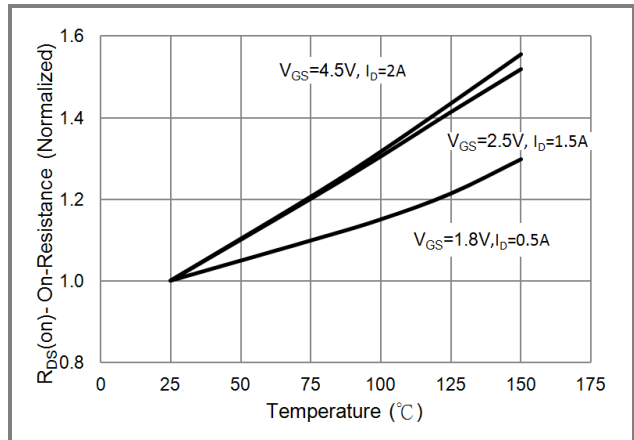


Fig.4 On-Resistance vs. Junction temperature

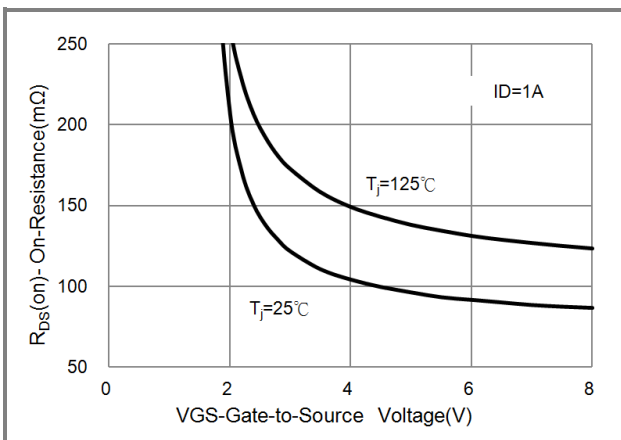


Fig.5 On-Resistance Variation with V_GS.

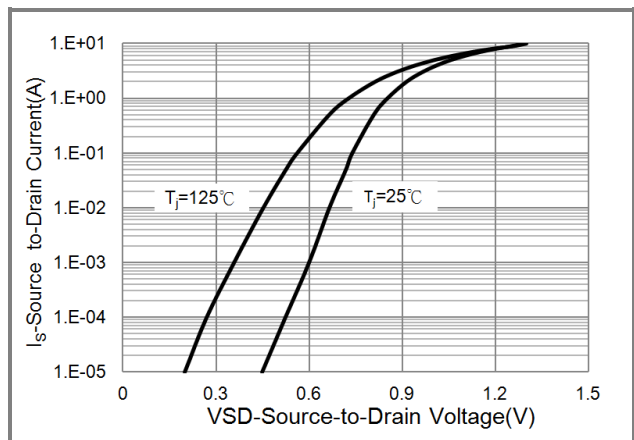


Fig.6 Body Diode Characteristics



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TYPICAL CHARACTERISTIC CURVES

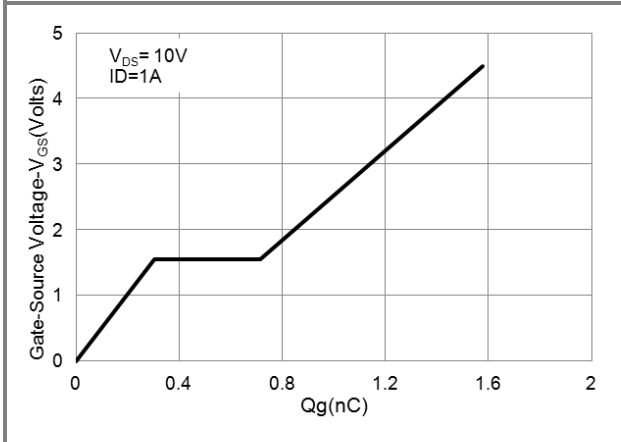


Fig.7 Gate-Charge Characteristics

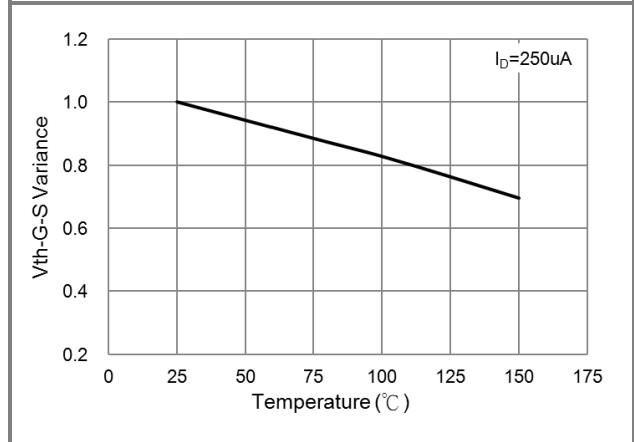


Fig.8 Threshold Voltage Variation with Temperature.

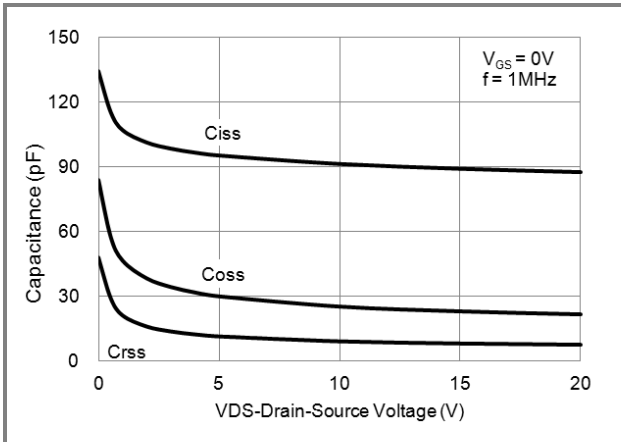


Fig.9 Capacitance vs. Drain-Source Voltage.

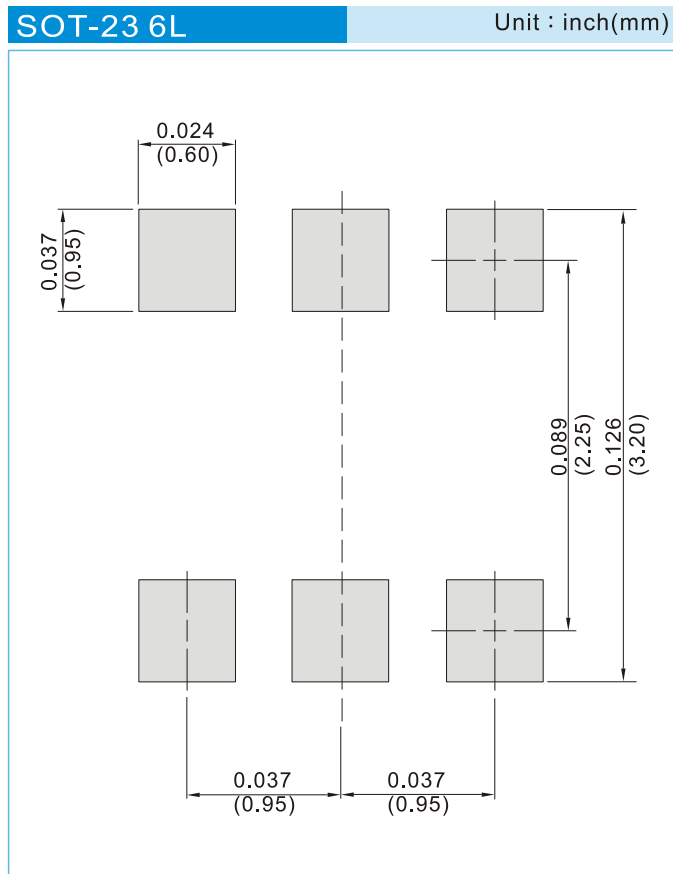


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Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJS6830_S1_00001	SOT-23 6L	3K pcs / 7" reel	SG0	Halogen free

Mounting Pad Layout





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